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Effect of amino acid doping on the dielectric properties of triglycine sulphate (TGS) crystals

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Abstract

Effect of amino acid (proline) doping on the dielectric properties of triglycine sulphate has been studied. Pure and proline doped triglycine sulphate (TGS) were grown from aqueous solution by solution growth technique at room temperature. The dielectric studies were carried out to identify the phase transition temperature and the dielectric behavior. The present study shows that there is an increase in the Curie temperature for the doped crystals.

Keywords: TGS crystals, proline doping, dielectric properties.

Introduction

Ferroelectic triglycine sulphate (TGS) is one of the most extensively studied ferroelectric materials, which finds wide application as room temperature IR detector. It also finds application in burglar alarms, medical vidicon room temperature, tubes operating at instrumentation and in pyroelectric detector. It undergoes a second-order phase transition at Curie temperature (322 K) from ferroelectric to paraelectric. The crystal structure of TGS is monoclinic below and above Curie temperature (Hoshino et al., 1959). The space group transforms from non-centrosymmetric P_{21} in the ferroelectric phase to centrosymmetrical P_{21/m} in the paraelectric phase. The cleavage plane is generally expressed as the b-plane and the spontaneous polarization $(P_s = 2.8 \mu C/cm^2)$ arises along crystallographic b-axis (Landolt-Bornstein, However, the TGS has a disadvantage that it depolarizes by thermal, electrical or mechanical means. An efficient way to stabilize the single domain state is practical by doping an optically active molecule into TGS. The practical substitution of an optically active molecule in the

place of glycine d molecule causes an internal bias field, which makes the crystal permanently polarized (Nakatani, 1973). Many authors investigated the effect of doping of various amino acids on TGS (Bye et al., 1972; Aravazhi, 1997a,b; Meera et al., 2000). The effect of organic dopants on TGS and rare earth ions dopant with TGS have also been investigated (Mihaylova & Stoyanov, 1996; Meera et al., 2001; Muralidharan et al., 2002; Theresita Shanthi et al., 2009; Selvarajan et al., 2008). In recent years, the interest in studying the pure and doped TGS crystals has increased because of their promise in various devices. In the present work we have chosen the amino acid proline as dopant because proline ions are expected to play a partial role for the spontaneous polarization in TGS crystal thereby increase the dielectric constant and Tc due to its intrinsic dipole moment. The objective of the present work was to investigate the effect of proline addition on the growth and dielectric properties of TGS crystal.

Experimental procedure

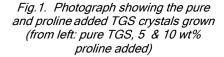
Growth of TGS

Triglycine sulphate (TGS) was synthesized (Theresita Shanthi *et al.*, 2009) by taking glycine and sulphuric acid in the molar ratio 3:1. Glycine reacts with sulphuric acid as follows:

 $3(NH_2CH_2COOH)+H_2SO_4\rightarrow (NH_2CH_2COOH)_3H_2SO_4$

The required amount of sulphuric acid was diluted with doubly distilled water. Then, the calculated amount of glycine was added and dissolved in diluted H_2SO_4 . The solution was heated until the salt got recrystallized. Extreme care was taken during recrystallization to avoid the oxidation of glycine. Hence, the solution temperature was always maintained below $60^{\circ}C$. The recrystallized

TGS salt was dissolved in doubly distilled water. In this way the natural impurity content of TGS salt was minimized. A saturated solution of TGS at room temperature was prepared using twice crystallized salt. solution was filtered using a high quality filter paper. The amino acid proline (5 and 10 wt%) was added to the saturated solution, till the equilibrium was attained. The solution was kept in glass vessels covered with perforated filter paper for slow evaporation at room temperature. Slow evaporation technique employed for crystal growth. Good auality transparent crystals were harvested after 25 days. The grown crystals were shown in Fig.1.





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polarization. In presence of an applied electric field, domains that are aligned with the direction of the field will grow at the expense of the less well aligned domains. Thus the observed enhancement in the dielectric constant at low frequency could be attributed to the multidomain state of the proline doped sample. As the frequency increases, a point will be reached where the space charge cannot sustained and comply with the external field giving rise to diminishing values of dielectric constant. Above this frequency the domain wall motion

contribution to dielectric constant was nearly the same for

pure and doped crystals (Parimalaselvi et al., 2010). The temperature dependence of dielectric constant (ε_r) obtained for the grown crystals for 100 Hz frequency is provided in Fig.2a and for 1 KHz frequency in Fig. 2b. The temperature dependence of dielectric loss (tan δ) obtained for the frequency 100 Hz is presented in Fig.3a and for 1 KHz in Fig. 3b. The dielectric constant and the dielectric loss values increases with the increase in temperature for both the frequencies up to the transition temperature and then decreases. The doped crystals have higher dielectric constant values compared to that of pure TGS. Increase in dielectric constant of doped TGS crystals at transition temperature attributed to free charge carriers created by the dopant.

The Curie point Tc for all the samples was not found to be the same. A small shift in temperature is found for doped TGS crystals. The dielectric constant is small at lower temperature, which increases with temperature and rises sharply up to the Curie point for both the frequencies. Above Tc the dielectric constants decreases suddenly and obey Curie-Wess law. Variation of ε_r with temperature is generally attributed to the crystal expansion, the electronic and ionic polarizations and the presence of impurities and crystal defects. The variation of ε_r at low temperature is mainly due to the expansion and electronic and ionic polarization. At higher temperatures, the increase is mainly attributed to the thermally generated charge carriers and impurity dipoles. The AC conductivity shows the same behavior (Fig.4a and 4b).

Fig. 5. shows the temperature dependence of DC conductivity (σ_{dc}), It can be seen that, for all TGS systems the DC conductivity increases with the increase in temperature. The defect concentration will increase exponentially with temperature and consequently the electrical conduction also increases. The addition of impurity further increases the electrical conduction in the temperature region considered. The conduction region is considered in the present study seems to be connected to mobility of vacancies.

Conclusions

Single crystals of pure and proline added Triglycine sulphate (TGS) were grown by slow evaporation method. The grown crystals are transparent and with well defined external appearance. Capacitance and dielectric loss

The sample crystals cleaved perpendicular to the polar axis with thickness about 4 mm having graphite coating on the opposite faces was placed between two brass electrode and thus parallel plate capacitor was formed. The capacitance and dielectric loss ($tan \delta$) were measured using the conventional two probe technique (Joseph John et al., 2007; Joseph John & Mahadevan, 2008) at various temperatures ranging from 300 to 357 K using an LCR meter (Model APLAB with two frequencies, namely 100Hz and 1 kHz). The dielectric constant was calculated using the relation:

 $C_{cry} - C_{air}(1-(A_{crys}/A_{air}))$ $\epsilon_{r} = \underbrace{\hspace{1cm}}_{x} (\ A_{air}/\ A_{crys}) \ , \ C_{air}$ Where, C_{crys} is the capacitance with crystal (including air), Cair is the capacitance of air, A_{crys} is the area of the crystal touching the electrode and Aair is the area of electrode. The AC electrical conductivity (σ_{ac}) was calculated using the relation $\sigma_{ac} = \epsilon_o \epsilon_r \omega \tan \delta$ where ϵ_o is the permittivity of free space(8.85 x 10⁻¹² Farad/m) and ω is the angular

frequency ($\omega = 2 \pi f$, f = 100 Hz & 1kHz).

The resistances of the crystals were measured using a thousand Meg ohmmeter. The observations were made while cooling the sample. The dimensions of the crystals were measured using a traveling microscope. The DC conductivity (σ_{dc}) of the crystal was calculated using the

relation σ_{dc} = d / (RA) where d is the thickness of the sample, A is the area of the sample and R is the measured resistance.

Results and discussion

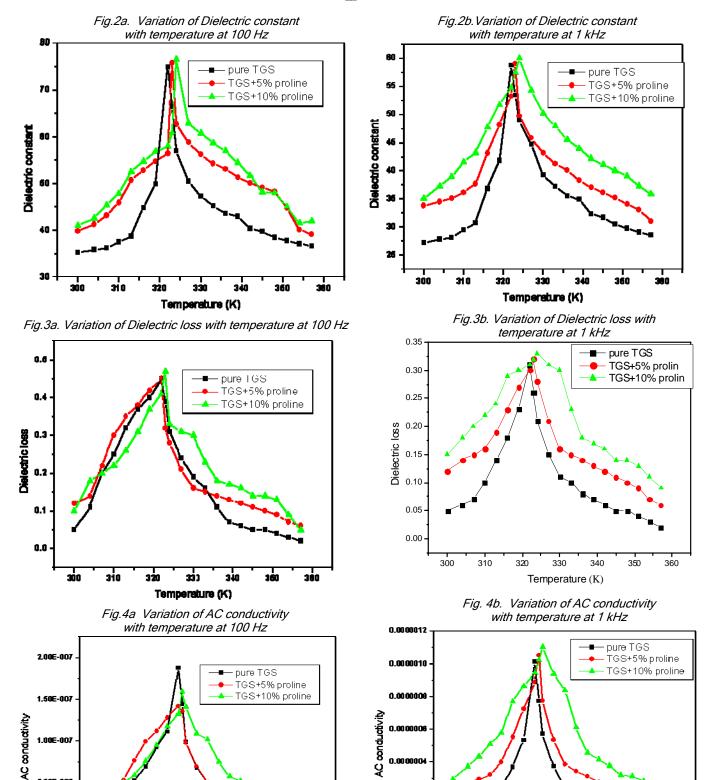
The term dielectric applies to the material properties governing the interaction between matter electromagnetic field. Induced or permanent electric polarization or magnetization of matter as a function of static or alternating electric, magnetic or electromagnetic field constitutes the dielectric properties of the material. The dielectric constant is one of the basic electrical properties of solids. Various polarization mechanisms in solids such as atomic polarization of the lattice, orientational polarization of diploes and space charge polarizations can be understood very easily by studying the dielectric properties as a function of frequency and temperature for crystalline solids (Wagner & Hantemann, 1950; Rao & Somakula 1965; Govinda & Rao, 1975) These investigations help in detecting the structural phase transitions taking place in solids when abrupt properties changes in dielectric are Particularly, the presence of a dielectric between the plates of a condenser enhances the capacitance. The effect makes material with dielectric constant useful in capacitor technology.

The magnitude of the dielectric constant depends on the degree of polarization charge displacement in the crystals. The electronic exchange of the number of ions in the crystals gives local displacement of electrons in the direction of applied field that gives polarization. Ferroelectric domains are areas of such local dipole alignment with an associated net dipole moment and net



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310

320

330

Temperature (K)

340

350

5.00E-008

0.00E+000

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0.0000002

0.0000000

330

Temperature (K)

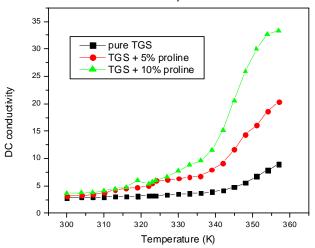
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320

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Fig.5. Variation of DC electrical conductivity with temperature



tangent (tan δ) measurements were carried out for the grown crystals at various temperatures ranging from 300 to 357 K using an LCR meter with frequencies of 100 Hz and 1 kHz. Dielectric constant and AC electrical conductivity were determined from the measured capacitance and tan δ values. The shift in the Curie temperature from 322 to 324 K in the doped crystals is due to the presence of high polarization capacity of proline. DC electrical conductivity was also measured at various temperatures and found to increase with increasing temperature.

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